

05.13-04

Express Mail No. EV 346 810 952 US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Bruce FAURE

Confirmation No. 7062

Application No.: 10/716,901

Group Art Unit: 2812

Filing Date: November 18, 2003

Examiner:

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Atty. Docket No.: 4717-12500

For: METHOD FOR FABRICATING A CARRIER

SUBSTRATE

SUPPLEMENTAL-INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Sir:

Pursuant to applicant's duty of disclosure under 37 C.F.R. 1.56, applicant submits herewith twenty-five (25) references for the Examiner's review and consideration. These references were cited in the European Search Report and a copy is enclosed.

These references are listed on the enclosed Form PTO-1449. It is respectfully requested that these references be made of record in this application by the Examiner's completion and return of the PTO Form 1449.

No fee is believed to be due for the filing of this statement as it is being submitted prior to an initial office action for this application. Should any fees be required, however, please charge such fees to Winston & Strawn LLP Deposit Account No. 50-1814.

Date: 5/11/04

Respectfully submitted,

Allan A. Fanucci

(Reg No. 30.256)

WINSTON & STRAWN LLP CUSTOMER NO. 28765

(212) 294-3311

Enclosures

NY:863414.1



LIST OF REFERENCES CITED BY APPLICANT (Use several sheets if necessary)

ATTY. DOCKET NO.:	APPLICATION NO.;			
4717-12500	10/716,901			
APPLICANT:				
Bruce FAURE				
FILING DATE:	GROUP:			
November 18, 2003	2812			

				U.S.	PATE	NT DOCUMENTS				
*EXAMINER INITIAL		DOCUMENT NUMBER]	DATE		NAME	CLASS	SUBCLASS	FILING APPRO	DATE I
	AA	5,374,564	12/	1994	Brue	1	437	24		
	AB	6,051,849	4/20	000	Davi	s et al.	257	103		
	AC	6,086,673	7/20	000	Molr	narq	117	102		
	AD	6,113,685	9/20	000	Wan	g et al.	117	3		
	AE	6,146,457	11/	/2000	Solo	mon	117	90		
	AF	6,303,405 B1	10,	/2001	Yosł	nida et al.	438	46		
	AG	6,440,823 B1	8/	2002	Vauc	lo et al.	438	478		
	АН	6,478,871 B1	11,	/2002	Shea	ly et al.	117	84		
	ΑI	2002/0068201 A1	6/.	2002	Vaud	io et al.	428	704		
	AJ	2002/0011599 A1	1/	2002	Moto	oki et al.	257	76		
	1		•	FORE	IGN PA	TENT DOCUMENTS	•	•	•	
		DOCUMENT NUMBER	DATE		ГЕ	COUNTRY	CLASS	SUBCLASS	TRANS	LATION
									YES	NO
	AK	EP 1 361 298 A1		11/20	03	Europe			x	
-	AL	EP 1 298 234 A2		4/200	2	Europe			x	
	AM	FR 2 810 159 A1		12/20	01	France			x	
	AN	FR 2 774 511		8/199	9	France			x	
	AO	FR 2 681 472		3/1993		France			X	
	AP	JP 2002343718 with English Abstract		11/20	02	Japan			X	
	AQ	WO 02064865 A1 wi English Abstract	th	8/200	2	PCT			X	
	AR	WO 03/043066 A2	5/2003		3	PCT			x	

		nt uthor, Title, Date, Pertinent Pages, Etc.)		
AS	R. Lantier et al., "Influence of the first preparation steps on the properties of GaN layer grown on 6H-SIC by MBE", , MRS Internet J. Nitride Semicond. Res. 4S1, G3.50 (1999)			
AT	J. Cao et al, "Improved quality GaN by growth on compliant silicon-on-insulator substrate using metalorganic chemical vapor deposition", Journal of Applied Physics, Vol. 83, No.7 (1998).			
AU		IN/GaN strained multi-layers on threading alternate supply of metalorganics and NH ₃ ", pp. 155-1 58 (2002),		
AV	Motoaki Iwaya et al., "Realization of crack-free and high-quality thick AI _x Ga _{1-x} N for UV optoelectronics using low-temperature interlayer", Applied Surface Science Vol.159-160 pp. 405-413 (2000)			
AW	H. Amano et al., "Metalorganic vapor phase epitaxial growth of a high quality GaN fill using an AIN buffer layer", Applied Physics Letters, Vol. 48, No. 5, pp. 353-355 (1986)			
AX	Y. Ujiie et al., "Epitaxial lateral overg Applied-Physics, Vol. 28, No. 3; pp. L.	growth of GaAs on a Si substrate", Japanese Journal 337-L339 (1989)		
AY	B. Beaumont, Ph. et al., "Epitaxial lateral overgrowth of GaN", phys. stat. sol. (b) 227, No 1, 1-43 (2001)			
AZ				
	EXAMINER	DATE CONSIDERED		

in conformance and not considered. Include copy of this form with next communication to applicant.



To: Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

The following items listed below are being filed herewith with the USPTO on May 11, 2004

Express Mail No. EV 346 810 952 US				
Attorney Docket No.	Appln. Serial No./ Patent No.	Items - Documents filed on May 10, 2004		
4717-12500	10/716,901	Supplemental Information Disclosure Statement, PTO 1449, 25 refs.		

Please acknowledge receipt of these items as received by returning the enclosed postcards with the date of receipt of May 11, 2004

NY:863041.2